# Complementary Dual General Purpose Amplifier Transistor

## **PNP and NPN Surface Mount**

#### **Features**

• High Voltage and High Current:  $V_{CEO} = 50 \text{ V}$ ,  $I_C = 200 \text{ mA}$ 

• High  $h_{FE}$ :  $h_{FE} = 200 \sim 400$ 

• Moisture Sensitivity Level: 1

• ESD Rating

• Human Body Model: 3A

Machine Model: C

• AEC-Q101 Qualified and PPAP Capable

• S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements

 These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant\*

## **MAXIMUM RATINGS** $(T_A = 25^{\circ}C)$

Rating	Symbol	Value	Unit
Collector-Base Voltage	V <sub>(BR)CBO</sub>	60	Vdc
Collector-Emitter Voltage	V <sub>(BR)CEO</sub>	50	Vdc
Emitter-Base Voltage	V <sub>(BR)EBO</sub>	7.0	Vdc
Collector Current - Continuous	Ic	200	mAdc

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Power Dissipation	P <sub>D</sub>	380	mW
Junction Temperature	TJ	150	°C
Storage Temperature	T <sub>stg</sub>	-55 to +150	°C

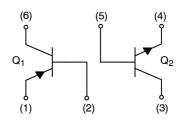


## ON Semiconductor®

http://onsemi.com



SC-74 CASE 318F STYLE 3



### **MARKING DIAGRAM**



R9 = Specific Device Code M = Date Code

= Pb-Free Package

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
HN1B01FDW1T1G	SC-74 (Pb-Free)	3,000/Tape & Reel
SHN1B01FDW1T1G	SC-74 (Pb-Free)	3,000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

Q1: PNP ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
Collector–Emitter Breakdown Voltage $(I_C = 2.0 \text{ mAdc}, I_B = 0)$	V <sub>(BR)CEO</sub>	-50	-	Vdc
Collector–Base Breakdown Voltage ( $I_C$ = 10 $\mu$ Adc, $I_E$ = 0)	V <sub>(BR)</sub> CBO	-60	-	Vdc
Emitter–Base Breakdown Voltage ( $I_E = 10 \mu Adc, I_C = 0$ )	V <sub>(BR)EBO</sub>	-7.0	_	Vdc
Collector-Base Cutoff Current (V <sub>CB</sub> = 45 Vdc, I <sub>E</sub> = 0)	I <sub>CBO</sub>	-	-0.1	μAdc
Collector–Emitter Cutoff Current $ (V_{CE} = 10 \text{ Vdc, } I_B = 0) $ $ (V_{CE} = 30 \text{ Vdc, } I_B = 0) $ $ (V_{CE} = 30 \text{ Vdc, } I_B = 0, T_A = 80^{\circ}\text{C}) $	lceo	- - -	-0.1 -2.0 -1.0	μAdc μAdc mAdc
DC Current Gain (Note 1) (V <sub>CE</sub> = 6.0 Vdc, I <sub>C</sub> = 2.0 mAdc)	h <sub>FE</sub>	-200	-400	-
Collector-Emitter Saturation Voltage (I <sub>C</sub> = 100 mAdc, I <sub>B</sub> = 10 mAdc)	V <sub>CE(sat)</sub>	-0.15	-0.3	Vdc

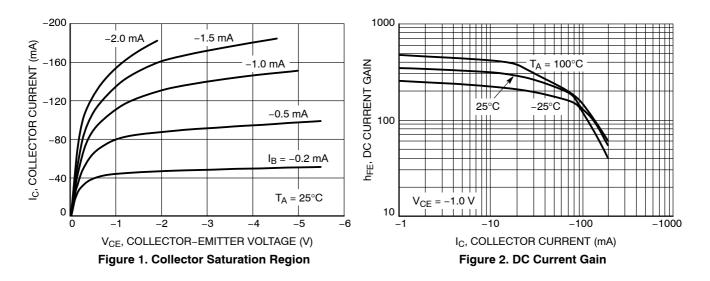
## Q2: NPN

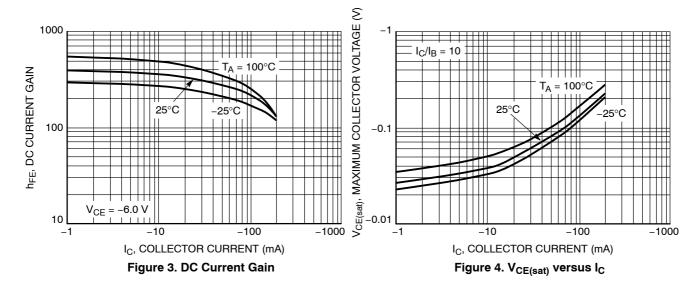
## **ELECTRICAL CHARACTERISTICS** ( $T_A = 25$ °C unless otherwise noted)

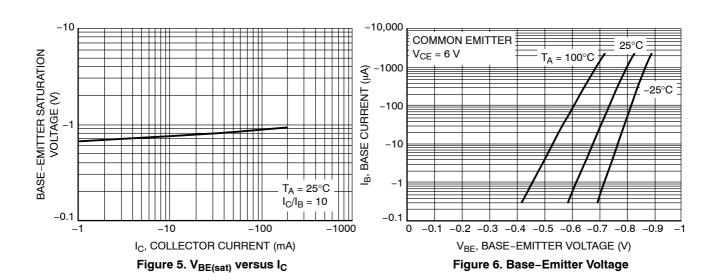
Characteristic	Symbol	Min	Max	Unit
Collector–Emitter Breakdown Voltage $(I_C = 2.0 \text{ mAdc}, I_B = 0)$	V <sub>(BR)CEO</sub>	50	-	Vdc
Collector–Base Breakdown Voltage ( $I_C = 10 \mu Adc, I_E = 0$ )	V <sub>(BR)CBO</sub>	60	-	Vdc
Emitter–Base Breakdown Voltage ( $I_E = 10 \mu Adc, I_C = 0$ )	V <sub>(BR)EBO</sub>	7.0	-	Vdc
Collector-Base Cutoff Current (V <sub>CB</sub> = 45 Vdc, I <sub>E</sub> = 0)	I <sub>CBO</sub>	-	0.1	μAdc
Collector–Emitter Cutoff Current $(V_{CE}=10\ Vdc,\ I_B=0)$ $(V_{CE}=30\ Vdc,\ I_B=0)$ $(V_{CE}=30\ Vdc,\ I_B=0,\ T_A=80^{\circ}C)$	I <sub>CEO</sub>	- - -	0.1 2.0 1.0	μAdc μAdc mAdc
DC Current Gain (Note 1) (V <sub>CE</sub> = 6.0 Vdc, I <sub>C</sub> = 2.0 mAdc)	h <sub>FE</sub>	200	400	-
Collector-Emitter Saturation Voltage (I <sub>C</sub> = 100 mAdc, I <sub>B</sub> = 10 mAdc)	V <sub>CE(sat)</sub>	0.15	0.25	Vdc

<sup>1.</sup> Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, D.C.  $\leq$  2%.

#### TYPICAL ELECTRICAL CHARACTERISTICS: PNP Transistor







#### TYPICAL ELECTRICAL CHARACTERISTICS: NPN Transistor

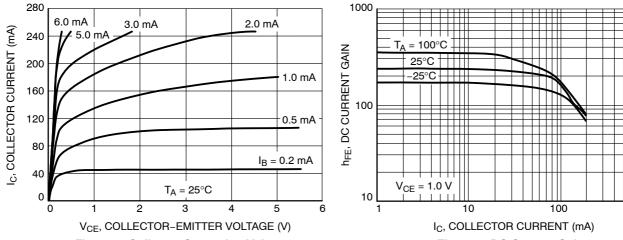
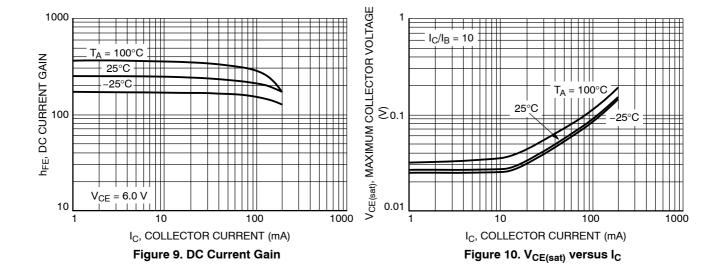
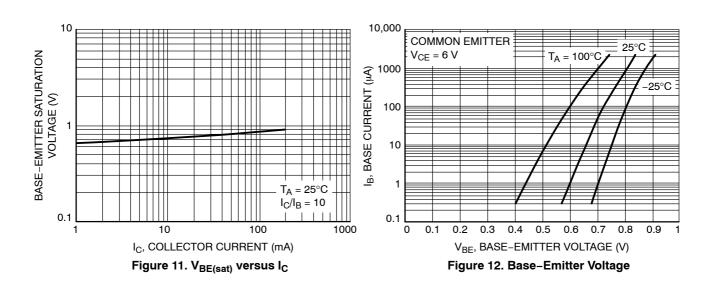


Figure 7. Collector Saturation Voltage

Figure 8. DC Current Gain

1000





## TYPICAL ELECTRICAL CHARACTERISTICS

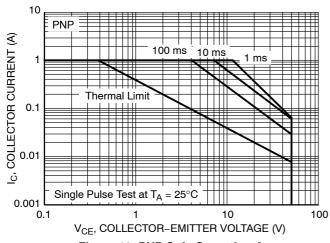


Figure 13. PNP Safe Operating Area

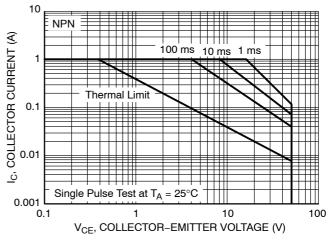
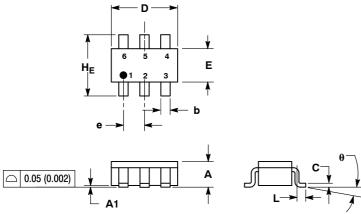


Figure 14. NPN Safe Operating Area

#### PACKAGE DIMENSIONS

SC-74 CASE 318F-05 ISSUE M



**SOLDERING FOOTPRINT\*** 

## 2.4 0.094 0.95 0.037 1.9 0.074 0.95 0.037 0.7 0.028 1.0 0.039 mm SCALE 10:1

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH
- MAXIMUM LEAD THICKNESS INCLUDES
  LEAD FINISH THICKNESS. MINIMUM LEAD
- OF BASE MATERIAL. 318F-01, -02, -03, -04 OBSOLETE. NEW STANDARD 318F-05.

THICKNESS IS THE MINIMUM THICKNESS

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.90	1.00	1.10	0.035	0.039	0.043
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.25	0.37	0.50	0.010	0.015	0.020
С	0.10	0.18	0.26	0.004	0.007	0.010
D	2.90	3.00	3.10	0.114	0.118	0.122
E	1.30	1.50	1.70	0.051	0.059	0.067
е	0.85	0.95	1.05	0.034	0.037	0.041
L	0.20	0.40	0.60	0.008	0.016	0.024
HE	2.50	2.75	3.00	0.099	0.108	0.118
θ	0°	-	10°	0°	-	10°

#### STYLE 3:

PIN 1. EMITTER 1

- 2. BASE 1 3. COLLECTOR 2
- 4. EMITTER 2 5. BASE 2
- 6. COLLECTOR 1

ON Semiconductor and un are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice on semiconductor and are registered readerlands of semiconductor Components industries, Ite (SCILLC) as Solitude services are injected in the chargest without further holice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

### **PUBLICATION ORDERING INFORMATION**

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA

Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910 Japan Customer Focus Center

Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative